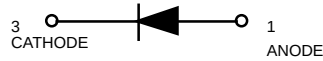


Switching Diode



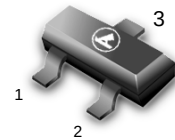
BAS16LT1

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V_R	75	Vdc
Peak Forward Current	I_F	200	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	500	mAdc

DEVICE MARKING

BAS16LT1 = A6



CASE 318-08, STYLE 8
SOT-23 (TO-236AB)

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C/W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	P_D	300	mW
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C/W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Reverse Voltage Leakage Current ($V_R = 75\text{Vdc}$)	I_R	—	1.0	μAdc
($V_R = 75\text{Vdc}, T_J = 150^\circ\text{C}$)		—	50	
($V_R = 25\text{Vdc}, T_J = 150^\circ\text{C}$)		—	30	
Reverse Breakdown Voltage ($I_{BR} = 100\mu\text{Adc}$)	$V_{(BR)}$	75	—	Vdc
Forward Voltage ($I_F = 1.0\text{mAdc}$)	V_F	—	715	mV
($I_F = 10\text{mAdc}$)		—	855	
($I_F = 50\text{mAdc}$)		—	1000	
($I_F = 150\text{mAdc}$)		—	1250	
Diode Capacitance ($V_R = 0, f = 1.0\text{MHz}$)	C_D	—	2.0	pF
Forward Recovery Voltage ($I_F = 10\text{mAdc}, t_r = 20\text{ns}$)	V_{FR}	—	1.75	Vdc
Reverse Recovery Time ($I_F = I_R = 10\text{mAdc}, R_L = 50\Omega$)	t_{rr}	—	6.0	ns
Stored Charge ($I_F = 10\text{mAdc}$ to $V_R = 5.0\text{Vdc}, R_L = 500\Omega$)	Q_S	—	45	pC

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

BAS16LT1

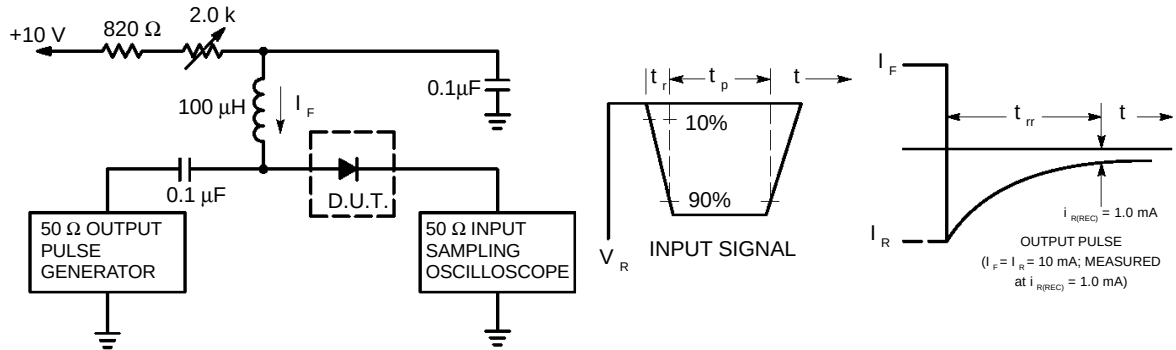


Figure 1. Recovery Time Equivalent Test Circuit

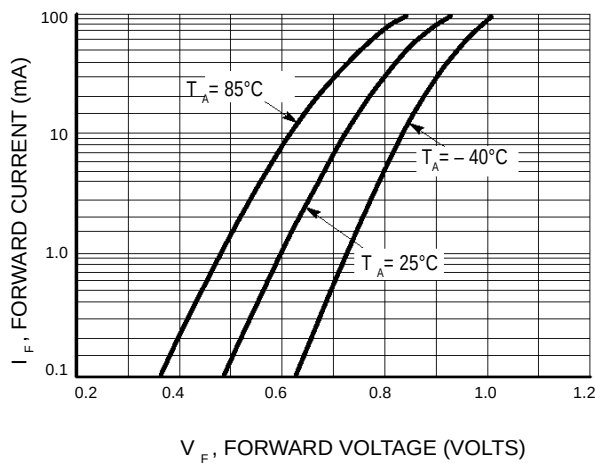


Figure 2. Forward Voltage

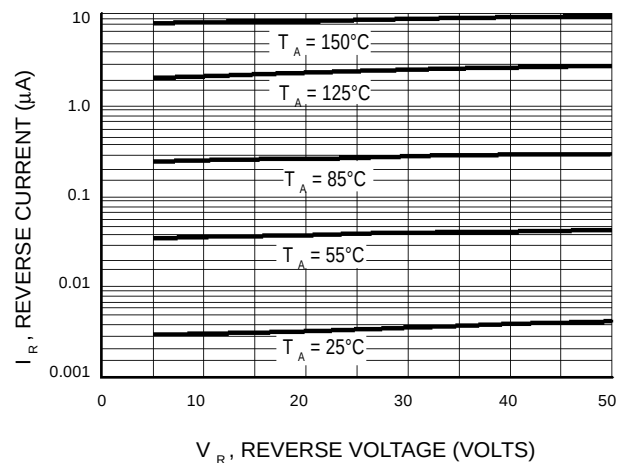


Figure 3. Leakage Current

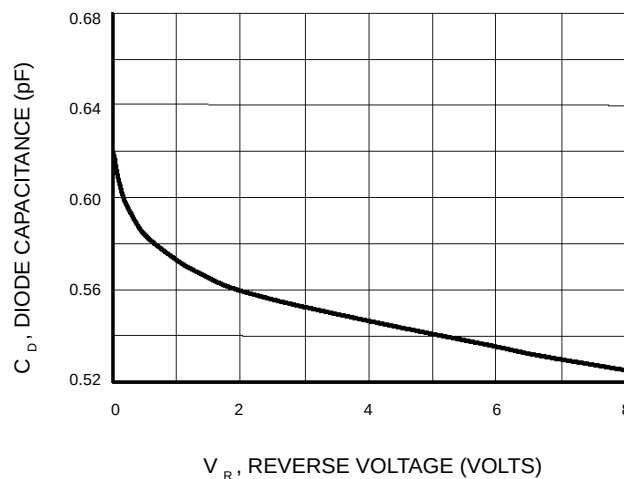


Figure 4. Capacitance